

10V Drive Nch MOSFET

R6004CND

● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) High-speed switching.
- 3) Wide SOA.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	2500
R6004CND		○

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	600	V
Gate-source voltage		V_{GSS}	±25	V
Drain current	Continuous	I_D *3	±4	A
	Pulsed	I_{DP} *1	±16	A
Source current (Body Diode)	Continuous	I_S	4	A
	Pulsed	I_{SP} *1	16	A
Avalanche current		I_{AS} *2	2	A
Avalanche energy		E_{AS} *2	1.1	mJ
Power dissipation		P_D *4	40	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 $L = 500 \mu H$, $V_{DD} = 50V$, $R_G = 25 \Omega$, $T_{ch} = 25^\circ C$

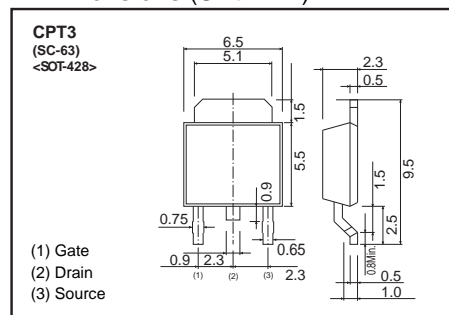
*3 Limited only by maximum temperature allowed.

*4 $T_C = 25^\circ C$

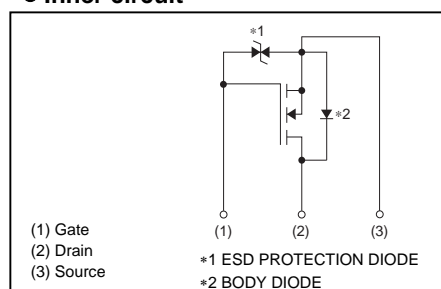
● Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to Case	$R_{th(ch-c)}$	3.13	°C / W

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	± 10	μA	$V_{GS} = \pm 25V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	600	-	-	V	$I_D = 1mA, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	-	-	100	μA	$V_{DS} = 600V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	2.5	-	4.5	V	$V_{DS} = 10V, I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	1.4	1.8	Ω	$I_D = 2A, V_{GS} = 10V$
Forward transfer admittance	$ Y_{fs} ^*$	1.2	-	-	S	$V_{DS} = 10V, I_D = 2A$
Input capacitance	C_{iss}	-	280	-	pF	$V_{DS} = 25V$
Output capacitance	C_{oss}	-	222	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	-	15	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	23	-	ns	$V_{DD} = 300V, I_D = 2A$
Rise time	t_r^*	-	28	-	ns	$V_{GS} = 10V$
Turn-off delay time	$t_{d(off)}^*$	-	44	-	ns	$R_L = 150\Omega$
Fall time	t_f^*	-	39	-	ns	$R_G = 10\Omega$
Total gate charge	Q_g^*	-	11	-	nC	$V_{DD} = 300V$
Gate-source charge	Q_{gs}^*	-	3	-	nC	$I_D = 4A$
Gate-drain charge	Q_{gd}^*	-	5	-	nC	$V_{GS} = 10V$

*Pulsed

● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD}^*	-	-	1.5	V	$I_S = 4A, V_{GS} = 0V$

*Pulsed

●Electrical characteristic curves

Fig.1 Typical Output Characteristics (I)

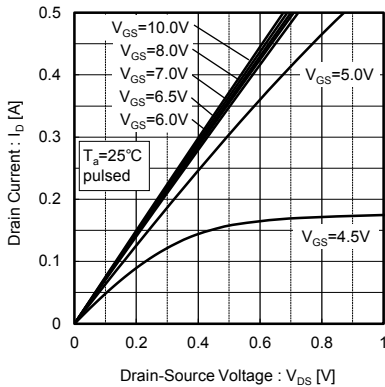


Fig.2 Typical Output Characteristics (II)

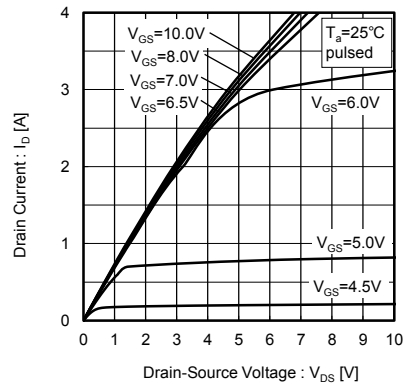


Fig.3 Typical Transfer Characteristics

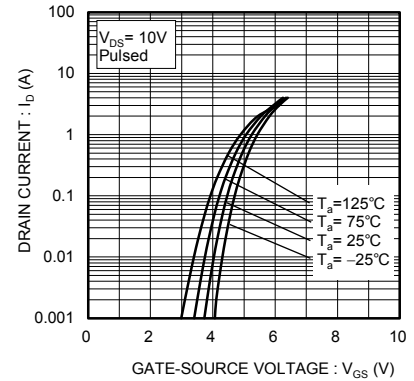


Fig.4 Gate Threshold Voltage vs. Channel Temperature

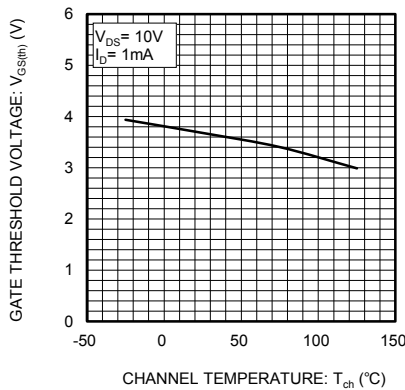


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

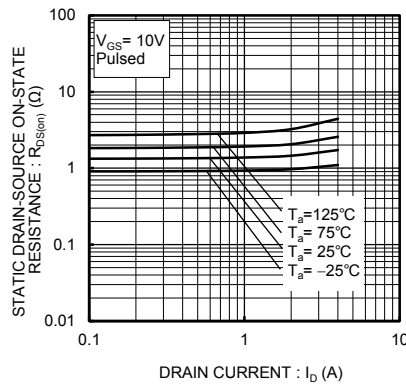


Fig.6 Static Drain-Source On-State Resistance vs. Gate Source

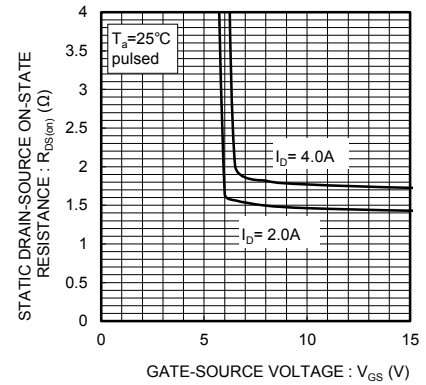


Fig.7 Static Drain-Source On-State Resistance vs. Channel Temperature

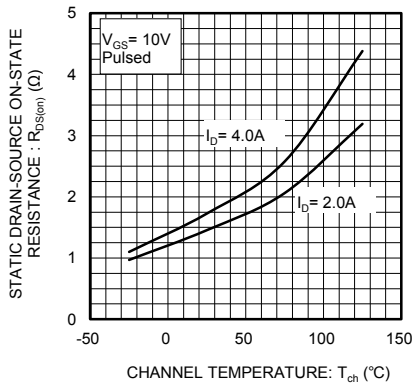


Fig.8 Forward Transfer Admittance vs. Drain Current

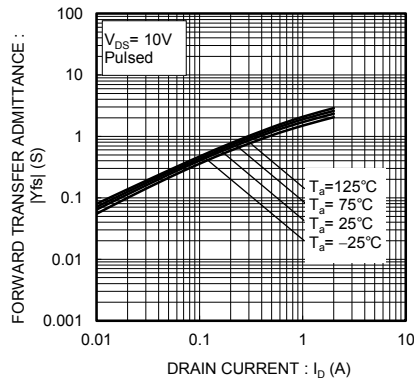


Fig.9 Source Current vs. Source-Drain Voltage

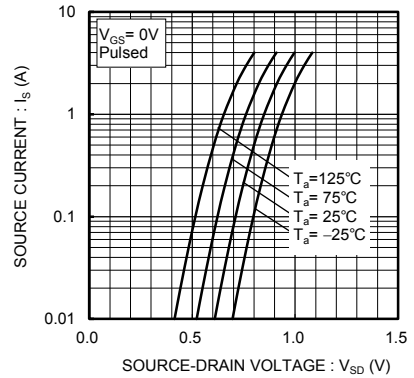


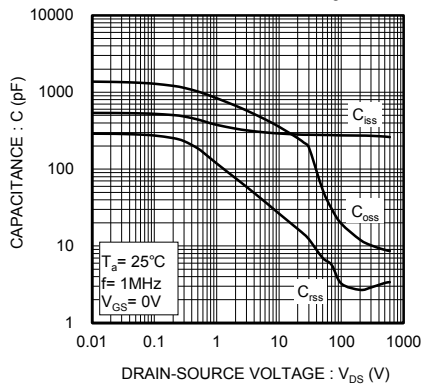
Fig.10 Typical Capacitance vs.
Drain-Source Voltage

Fig.11 Dynamic Input Characteristics

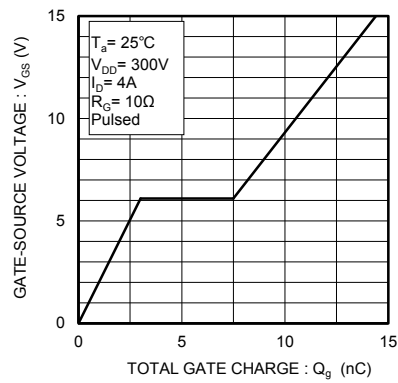
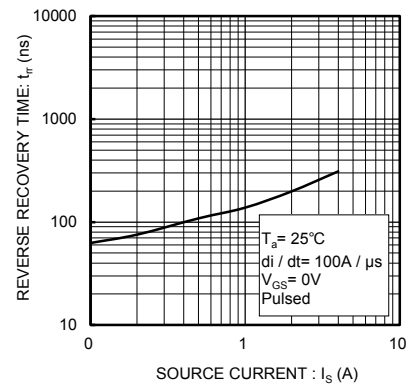
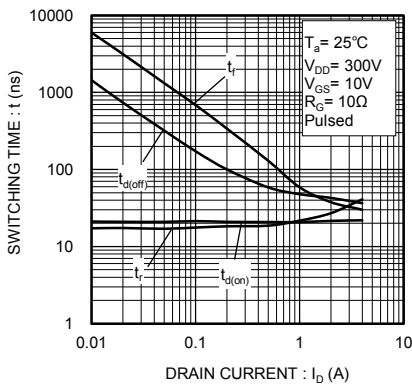
Fig.12 Reverse Recovery Time
vs. Source Current

Fig.13 Switching Characteristics



● Measurement circuits

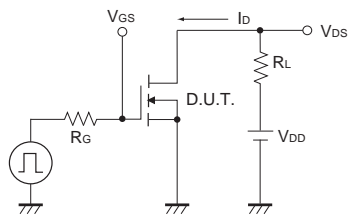


Fig.1-1 Switching Time Measurement Circuit

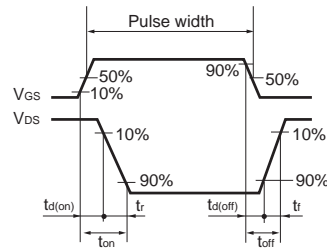


Fig.1-2 Switching Waveforms

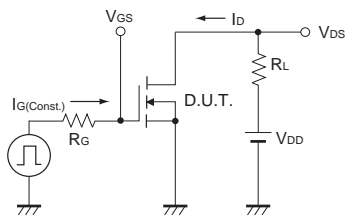


Fig.2-1 Gate Charge Measurement Circuit

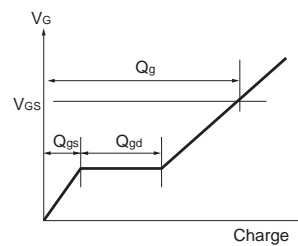


Fig.2-2 Gate Charge Waveform

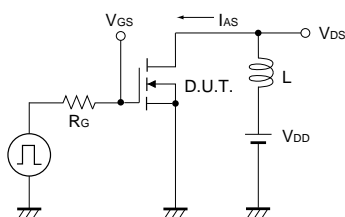


Fig.3-1 Avalanche Measurement Circuit

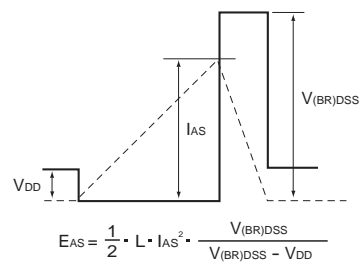


Fig.3-2 Avalanche Waveform

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